



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Application No.: 10/780,031 Confirmation No.: 9275  
First Named Inventor: Park, Jongmin Filing Date: 17 February 2004  
Group Art Unit: 2824 Examiner: Wendler, Eric J.  
Atty. Docket No.: R-0003 US  
Title: Technique for Programming Floating-gate Transistor Used in  
Circuitry Such as Flash EPROM  
Assignee(s): ProMOS Technologies Inc.

Mountain View, California  
22 November 2005

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**PRELIMINARY AMENDMENT**

Sir:

Please amend the above patent application in the following manner.

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